## **EAST Search History**

Ref #	Hits	Search Query	DBs	Default Operator	Plurals	Time Stamp
S12 2	3	"10308285"	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/12/20 16:42
S12 3	21	(organic near3 (display device element)) same (((two second) near3 anode) with thickness)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/12/20 16:44
S12 4	0	"10385453"	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/12/21 14:48
S12 5	3	"10/385453"	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/12/21 15:37
S12 6	40	(((multilayer two bilayer) near3 anode) same thickness) and 313/504-506.ccls.	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/12/21 15:57
S12 7	0	((two near3 layers) same (phtolithography) same etch\$4) and "445"/ "24".ccls.	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/12/21 15:51
S12 8	0	(layers same (phtolithography) same etch\$4) and "445"/\$.ccls.	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/12/21 15:51
S12 9	0	( (phtolithography) same etch\$4) and display and "445"/\$.ccls.	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/12/21 15:51
S13 0	7	((two near3 layers) same (photolithography) same etch\$4) and "445"/\$.ccls.	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/12/21 15:51

## **EAST Search History**

S13 1	13	(((multilayer two bilayer) near3 anode) same thickness) and 428/690.ccls.	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/12/21 15:58
S13 2	2	"6737800".pn.	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/12/21 15:59
S13 3	6	("20030057828"   "5550066"   "6124024"   "6366017"   "6392340"   "6639250").PN.	US-PGPUB; USPAT; USOCR	OR .	ON	2006/12/21 15:59
S13 4	. 2	("6737800").URPN.	USPAT	OR	ON	2006/12/21 16:03
S13 5	17	("20010001050"   "20020197394"   "20030141810"   "20040094768"   "6048573"   "6066357"   "6087196"   "6366016"   "6440877"   "6566153"   "6575800"   "6576975"   "6633121"   "6656519"   "6737800"   "6750792"   "6891326").PN.	US-PGPUB; USPAT; USOCR	OR	ON	2006/12/21 16:11
S13 6	0	(((double bilayer multilayer) near3 anode near3 form\$5) same etch\$4) and 438/29.ccls.	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/12/21 16:12
S13 7	0	(((double bilayer multilayer) near3 anode near3 form\$5) same etch\$4) and 427/66,67.ccls.	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/12/21 16:13
S13 8	38	(( anode near3 form\$5) same etch\$4) and 427/66,67.ccls.	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/12/21 17:47